

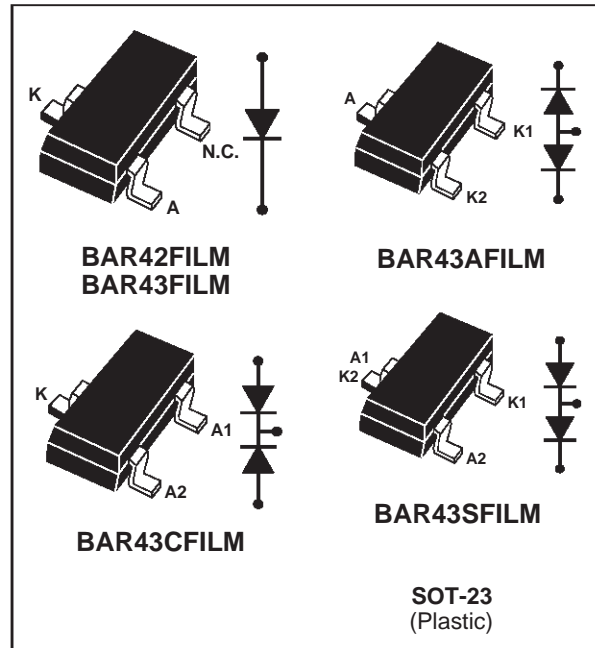


BAR42FILM BAR43/A/C/SFILM

SMALL SIGNAL SCHOTTKY DIODES

DESCRIPTION

General purpose metal to silicon diodes featuring very low turn-on voltage and fast switching.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		30	V
I_F	Continuous forward current		100	mA
I_{FSM}	Surge non repetitive forward current	tp=10ms sinusoidal	750	mA
P_{tot}	Power dissipation (note 1)	$T_{amb} = 25^\circ\text{C}$	250	mW
T_{stg}	Maximum storage temperature range		- 65 to +150	$^\circ\text{C}$
T_j	Maximum operating junction temperature *		150	$^\circ\text{C}$
T_L	Maximum temperature for soldering during 10s		260	$^\circ\text{C}$

Note 1: for double diodes, P_{tot} is the total power dissipation of both diodes.

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

THERMAL RESISTANCE

Symbol	Test conditions	Value	Unit
$R_{th(j-a)}$	Junction-ambient *	500	$^\circ\text{C/W}$

* Mounted on epoxy board with recommended pad layout.

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ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit	
V_{BR}	$T_j = 25^\circ\text{C}$	$I_R = 100\mu\text{A}$	30			V	
V_F^*	$T_j = 25^\circ\text{C}$	BAR 42FILM	$I_F = 10\text{ mA}$		0.35	0.4	V
			$I_F = 50\text{ mA}$		0.5	0.65	
		BAR 43FILM	$I_F = 2\text{ mA}$	0.26		0.33	
			$I_F = 15\text{ mA}$			0.45	
I_R^{**}	$T_j = 25^\circ\text{C}$	$V_R = 25\text{V}$			500	nA	
	$T_j = 100^\circ\text{C}$				100	μA	

Pulse test: * $t_p = 380\mu\text{s}$, $\delta < 2\%$
 ** $t_p = 5\text{ ms}$, $\delta < 2\%$

DYNAMIC CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
C	$T_j = 25^\circ\text{C}$	$V_R = 1\text{V}$	$F = 1\text{MHz}$		7		pF
t_{rr}	$T_j = 25^\circ\text{C}$ $I_{rr} = 1\text{mA}$	$I_F = 10\text{ mA}$ $R_L = 100\ \Omega$	$I_R = 10\text{ mA}$			5	ns
η^*	$T_j = 25^\circ\text{C}$ $F = 45\text{Mhz}$	$R_L = 50\text{ K}\Omega$ $V_i = 2\text{V}$	$C_L = 300\text{ pF}$ for BAR 43	80			%

* Detection efficiency

Fig. 1-1: Forward voltage drop versus forward current (typical values, low level).

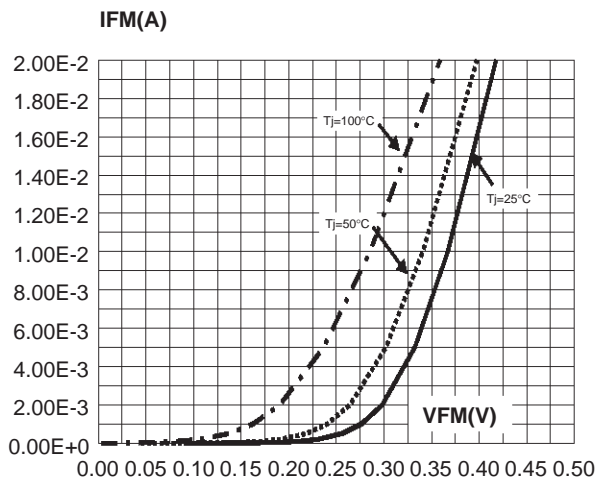


Fig. 1-2: Forward voltage drop versus forward current (typical values, high level).

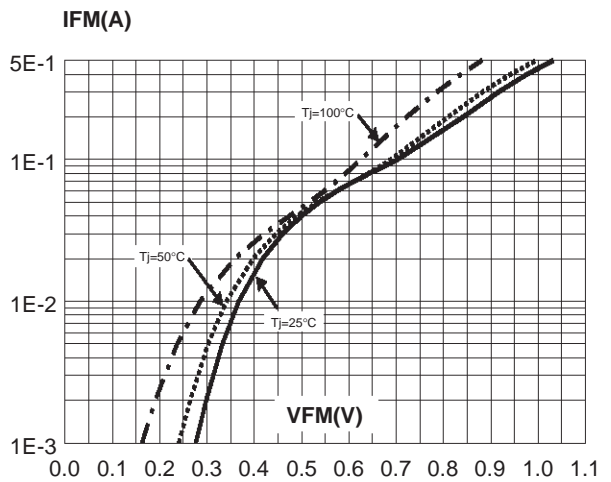


Fig. 2: Reverse leakage current versus reverse voltage applied (typical values).

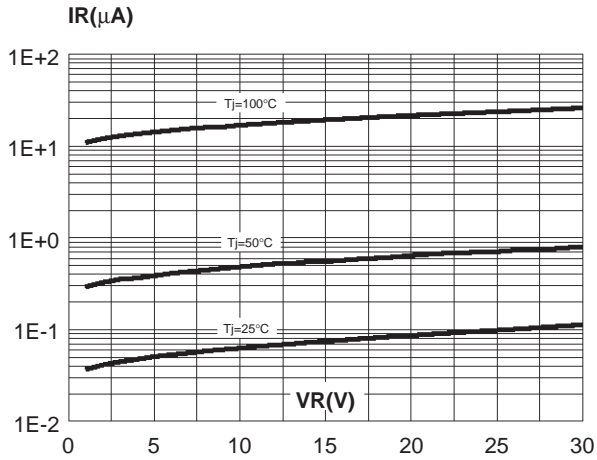


Fig. 4: Junction capacitance versus reverse voltage applied (typical values).

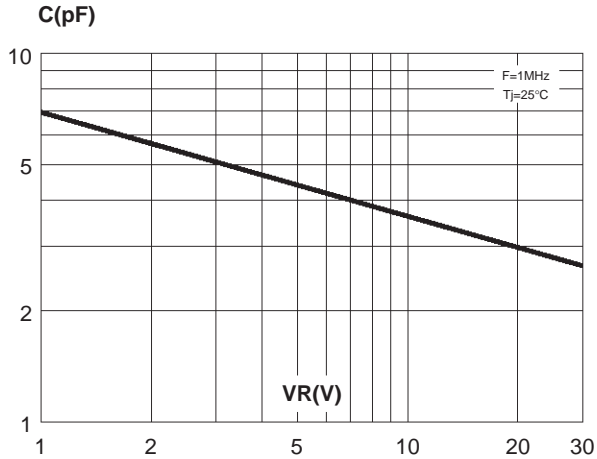


Fig. 6: Thermal resistance junction to ambient versus copper surface under each lead (Epoxy printed circuit board FR4, copper thickness: $35\mu m$).

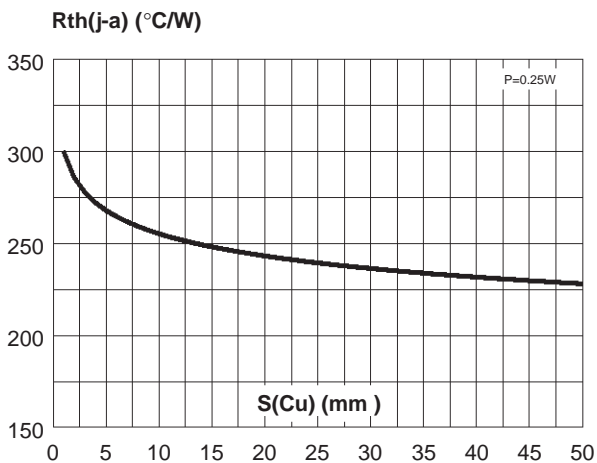


Fig. 3: Reverse leakage current versus junction temperature.

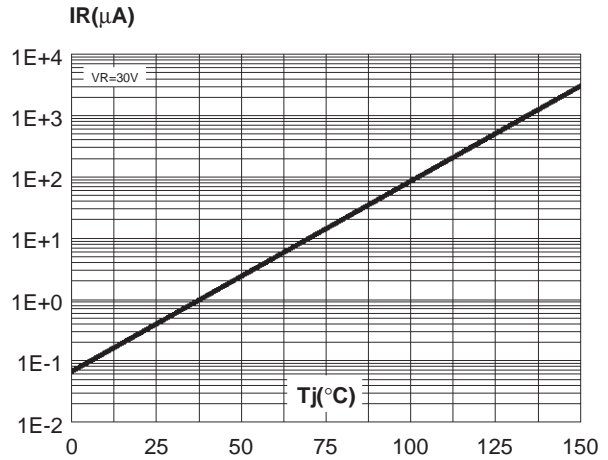
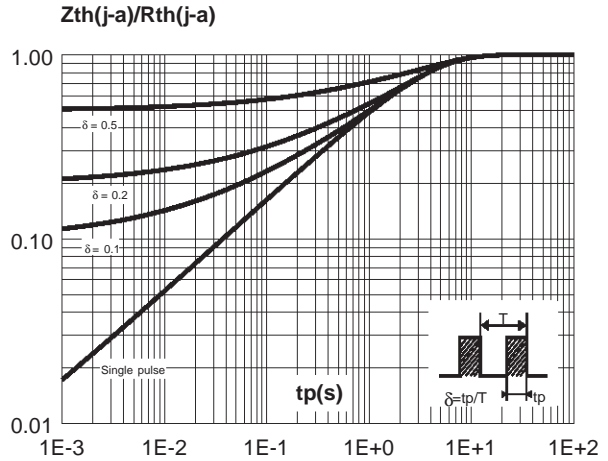
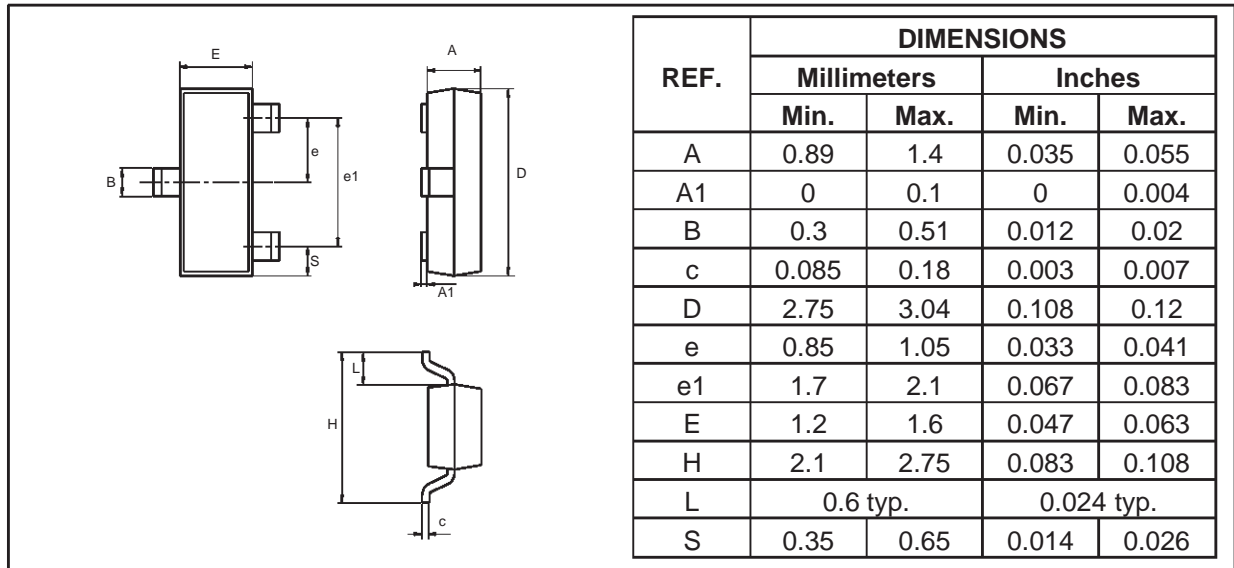


Fig. 5: Relative variation of thermal impedance junction to ambient versus pulse duration (epoxy FR4 with recommended pad layout, $e(Cu) = 35\mu m$).

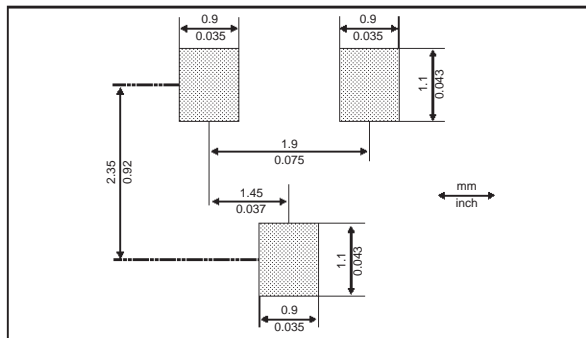


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PACKAGE MECHANICAL DATA SOT-23 (Plastic)



FOOT PRINT DIMENSIONS



Ordering type	Marking	Package	Weight	Base qty	Delivery mode
BAR42FILM	D94	SOT-23	0.01g	3000	Tape & reel
BAR43FILM	D95	SOT-23	0.01g	3000	Tape & reel
BAR43AFILM	DB1	SOT-23	0.01g	3000	Tape & reel
BAR43CFILM	DB2	SOT-23	0.01g	3000	Tape & reel
BAR43SFILM	DA5	SOT-23	0.01g	3000	Tape & reel

Epoxy meets UL94,V0

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